



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Peak Emission Wavelength: 850nm

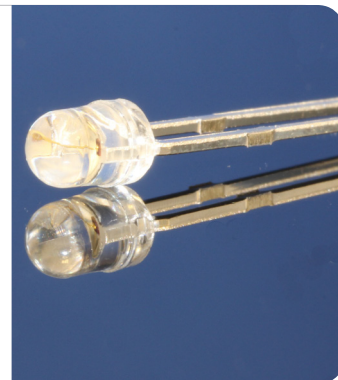
The MTE8600C consists of a 850nm high output infrared die in a water-clear 3mm plastic molded package. Custom package solutions and sorting are available.

FEATURES

- > High Output Power
- > Compact
- > High Reliability

APPLICATIONS

- > Optical Switches & Sensors
- > Fiber Optical Communication



Absolute Maximum Ratings (Ta=25°C)

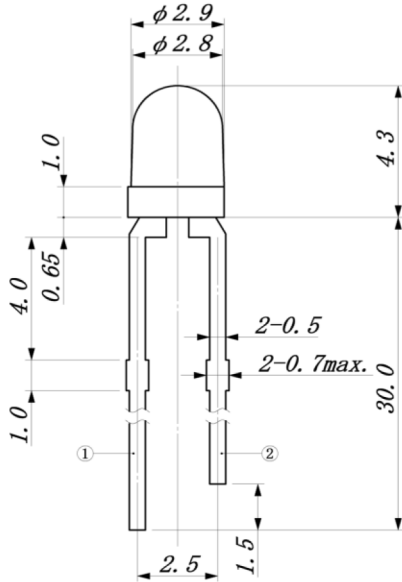


ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	1	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	190	mW
Operating Temperature Range	Topr	-20 ~ +80	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C
Junction Temperature	Tj	100	°C
Lead Soldering Temperature*2	Tls	260	°C

*1: Tw=10μsec, T=10msec. *2: Time 5Sec max, Position: Up to 3mm from the body.

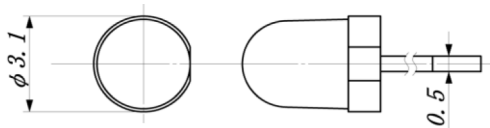
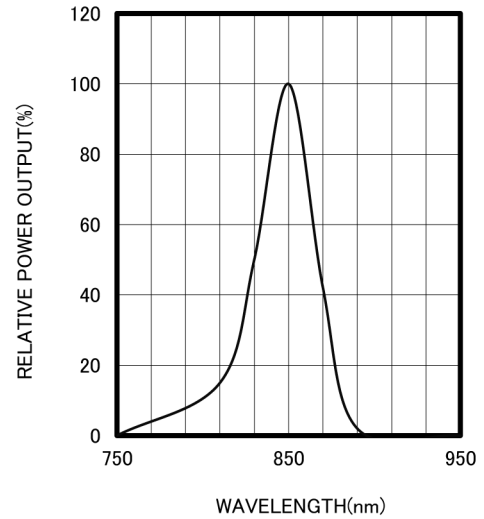
Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	--	28.0	--	mW
Forward Voltage	VF	IF=50mA	--	1.45	1.9	V
Reverse Current	IR	VR=5V	--	--	100	μA
Peak Emission Wavelength	λp	IF=50mA	--	850	--	nm
Spectral Line Half Width	Δλ	IF=50mA	--	30	--	nm
Half Intensity Beam Angle	Θ	IF=50mA	--	±25	--	deg

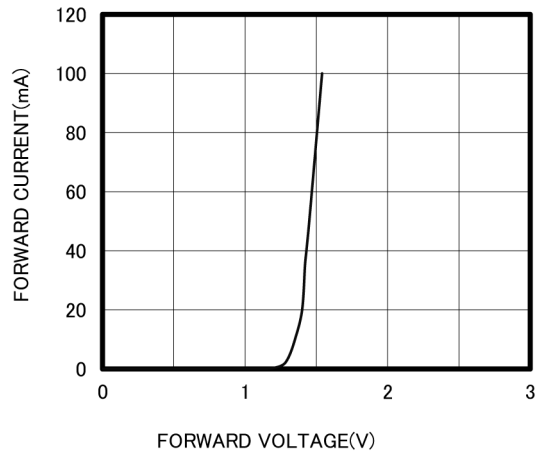


- ① Anode
- ② Cathode

SPECTRAL OUTPUT



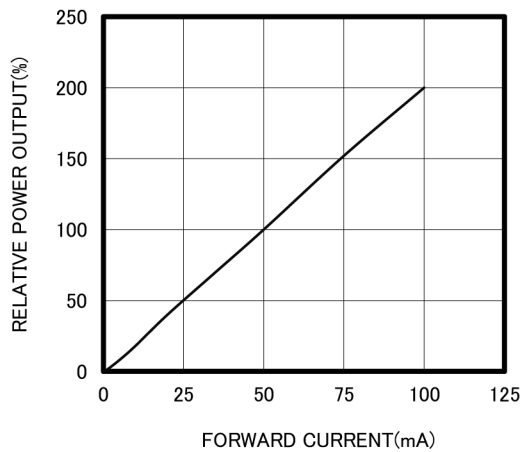
FORWARD I-V CHARACTERISTICS



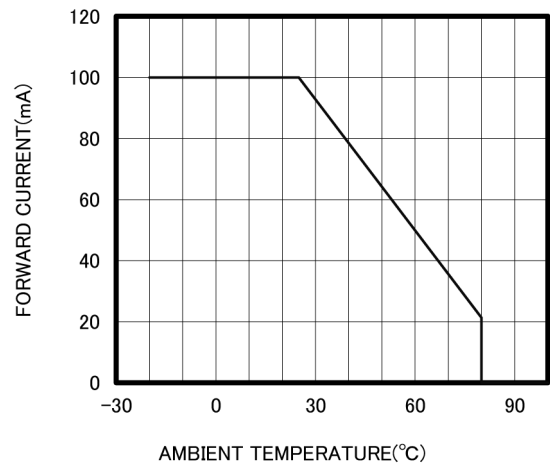
Unit: mm, Tolerance: ± 0.2

2012-05-17

RELATIVE POWER vs FORWARD CURRENT



THERMAL DERATING CURVE



RADIATION PATTERN

